

Array LED
2 mm LED, Diffused

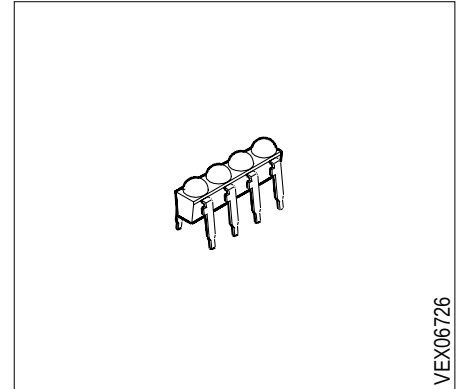
LR Z18x, LY Z181, LG Z18x

Besondere Merkmale

- eingefärbtes, diffuses Gehäuse
- als optischer Indikator einsetzbar
- als Mehrfachzeile verfügbar
- Störimpulsfest nach DIN 40839

Features

- colored, diffused package
- for use as optical indicator
- available as multiple array (LED)
- load dump resistant acc. to DIN 40839



Type	Anzahl der Lichtpunkte Number of Dots	Emissionsfarbe Color of Emission	Gehäusefarbe Color of Package	Lichtstärke Luminous Intensity $I_F = 10 \text{ mA}$ $I_V \text{ (mcd)}$	Bestellnummer Ordering Code
LR Z181-CO	1	red	red diffused	≥ 0.25	Q62703-Q1495
LR Z182-CO	2	red	red diffused	≥ 0.25	Q62703-Q1496
LR Z183-CO	3	red	red diffused	≥ 0.25	Q62703-Q1497
LR Z184-CO	4	red	red diffused	≥ 0.25	Q62703-Q1498
LR Z185-CO	5	red	red diffused	≥ 0.25	Q62703-Q1499
LR Z186-CO	6	red	red diffused	≥ 0.25	Q62703-Q1500
LR Z187-CO	7	red	red diffused	≥ 0.25	Q62703-Q1501
LR Z188-CO	8	red	red diffused	≥ 0.25	Q62703-Q1502
LY Z181-CO	1	yellow	yellow diffused	≥ 0.25	Q62703-Q1505
LG Z181-CO	1	green	green diffused	≥ 0.25	Q62703-Q1506
LG Z182-CO	2	green	green diffused	≥ 0.25	Q62703-Q1507
LG Z183-CO	3	green	green diffused	≥ 0.25	Q62703-Q1508
LG Z184-CO	4	green	green diffused	≥ 0.25	Q62703-Q1509
LG Z185-CO	5	green	green diffused	≥ 0.25	Q62703-Q1510
LG Z186-CO	6	green	green diffused	≥ 0.25	Q62703-Q1511
LG Z188-CO	8	green	green diffused	≥ 0.25	Q62703-Q1513

Streuung der Lichtstärke in einer Verpackungseinheit $I_{V \max} / I_{V \min} \leq 2.0$.

Luminous intensity ratio in one packaging unit $I_{V \max} / I_{V \min} \leq 2.0$.

Grenzwerte
Maximum Ratings

Bezeichnung Parameter	Symbol Symbol	Werte Values	Einheit Unit
Betriebstemperatur Operating temperature range	T_{op}	– 40 ... + 80	°C
Lagertemperatur Storage temperature range	T_{stg}	– 40 ... + 80	°C
Sperrschichttemperatur Junction temperature	T_j	+ 100	°C
Durchlaßstrom Forward current	I_F	30	mA
Stoßstrom Surge current $t \leq 10 \mu s, D = 0.005$	I_{FM}	0.5	A
Sperrspannung Reverse voltage	V_R	5	V
Verlustleistung Power dissipation $T_A \leq 25 \text{ °C}$	P_{tot}	80	mW
Wärmewiderstand Thermal resistance Sperrschicht / Luft Junction / air	$R_{th JA}$	750 ¹⁾	K/W

1) Auf Platine gelötet: Lötfläche $\geq 16 \text{ cm}^2$.

1) Soldered on PC board: pad size $\geq 16 \text{ cm}^2$.

Kennwerte ($T_A = 25\text{ °C}$)

Characteristics

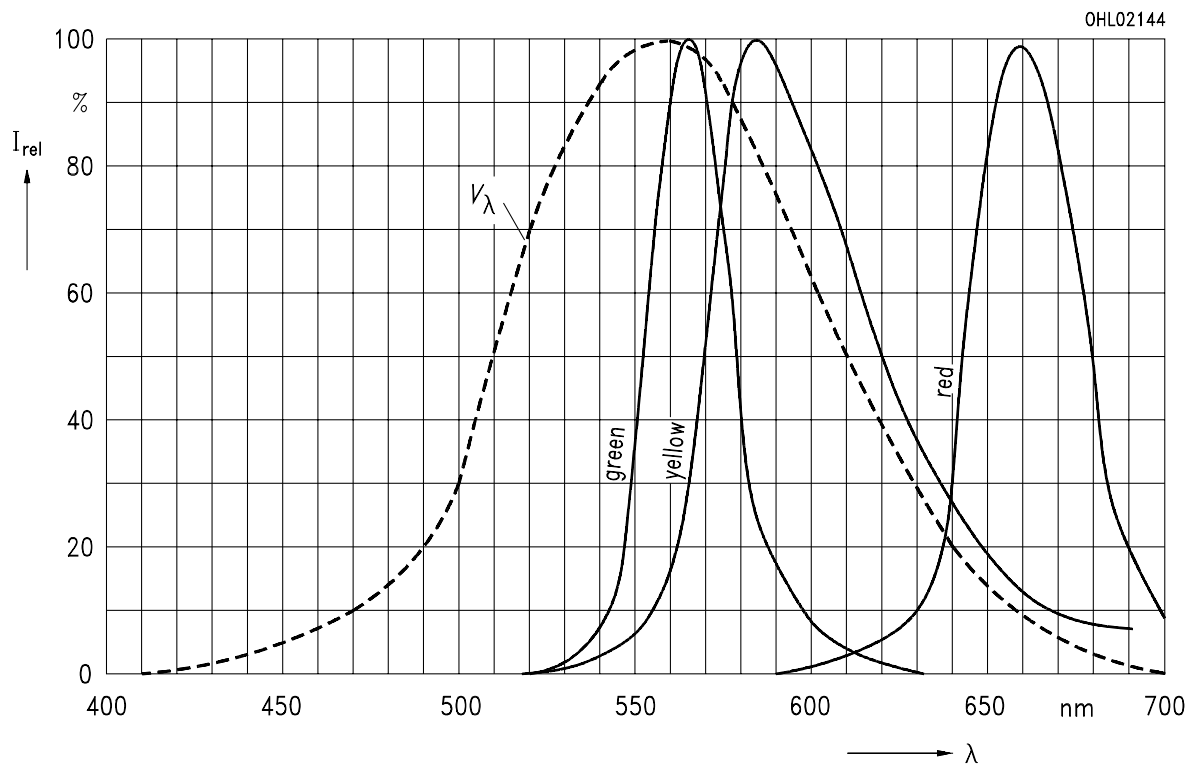
Bezeichnung Parameter	Symbol Symbol	Werte Values			Einheit Unit
		LR	LY	LG	
Wellenlänge des emittierten Lichtes (typ.) Wavelength at peak emission (typ.) $I_F = 20\text{ mA}$	λ_{peak}	660	586	565	nm
Dominantwellenlänge (typ.) Dominant wavelength (typ.) $I_F = 20\text{ mA}$	λ_{dom}	645	590	570	nm
Spektrale Bandbreite bei 50 % $I_{\text{rel max}}$ (typ.) Spectral bandwidth at 50 % $I_{\text{rel max}}$ (typ.) $I_F = 20\text{ mA}$	$\Delta\lambda$	35	45	25	nm
Abstrahlwinkel bei 50 % I_V (Vollwinkel) Viewing angle at 50 % I_V	2ϕ	100	100	100	Grad deg.
Durchlaßspannung (typ.) Forward voltage (max.) $I_F = 10\text{ mA}$	V_F V_F	1.6 2.0	2.0 2.6	2.0 2.6	V V
Sperrstrom (typ.) Reverse current (max.) $V_R = 5\text{ V}$	I_R I_R	0.01 10	0.01 10	0.01 10	μA μA
Kapazität (typ.) Capacitance $V_R = 0\text{ V}$, $f = 1\text{ MHz}$	C_0	25	10	15	pF
Schaltzeiten: Switching times: I_V from 10 % to 90 % (typ.) I_V from 90 % to 10 % (typ.) $I_F = 100\text{ mA}$, $t_p = 10\text{ }\mu\text{s}$, $R_L = 50\text{ }\Omega$	t_r t_f	120 50	300 150	450 200	ns ns

Relative spektrale Emission $I_{\text{rel}} = f(\lambda)$, $T_A = 25^\circ\text{C}$, $I_F = 20\text{ mA}$

Relative spectral emission

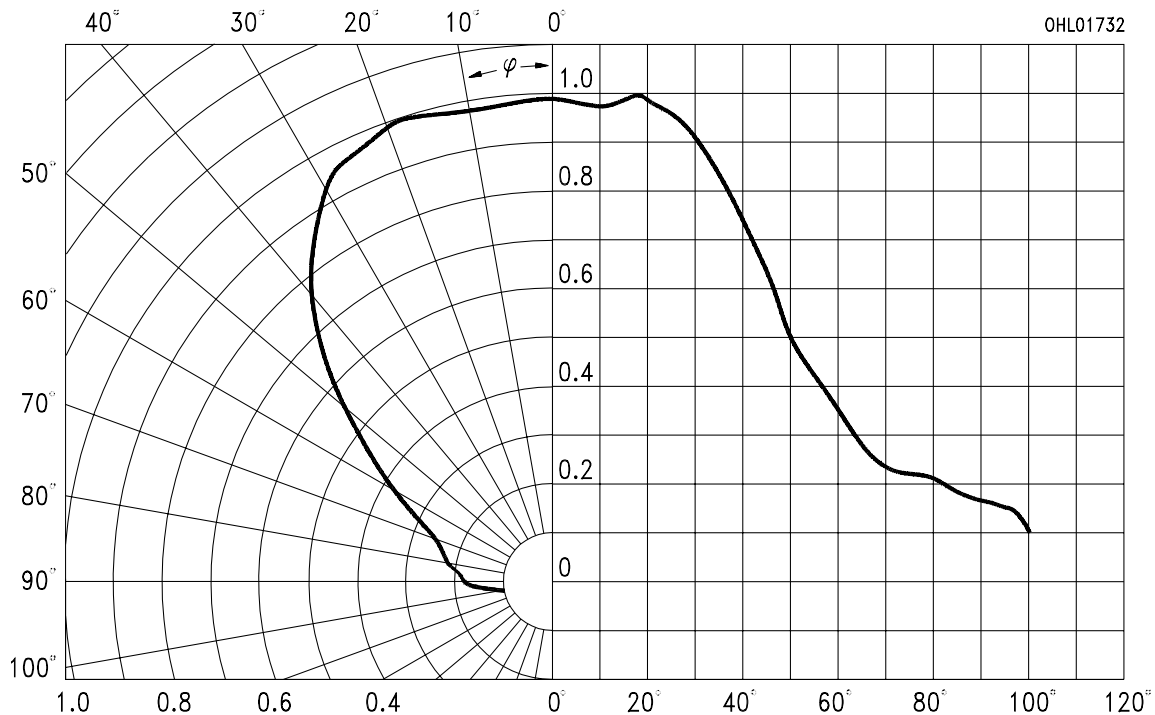
$V(\lambda)$ = spektrale Augenempfindlichkeit

Standard eye response curve



Abstrahlcharakteristik $I_{\text{rel}} = f(\varphi)$

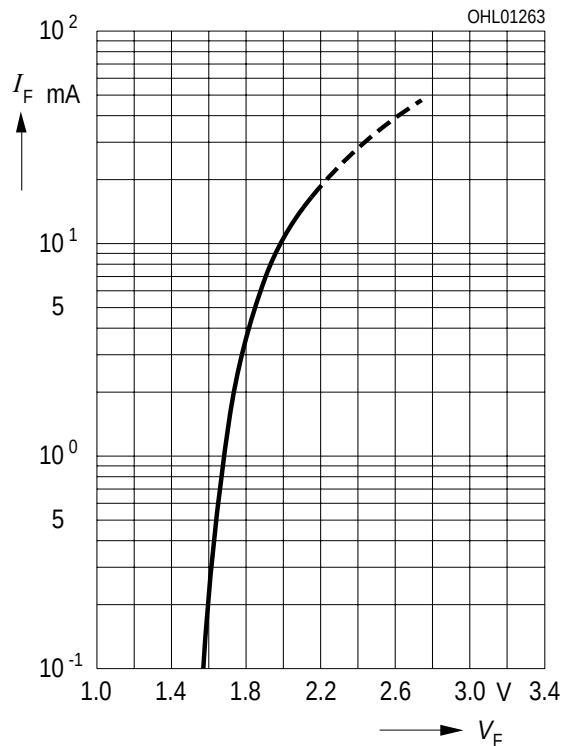
Radiation characteristic



Durchlaßstrom $I_F = f(V_F)$

Forward current

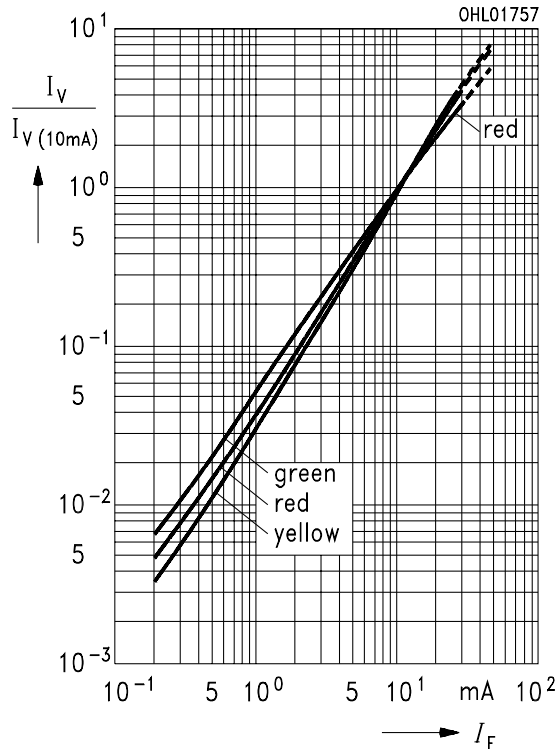
$T_A = 25^\circ\text{C}$



Relative Lichtstärke $I_V/I_{V(10\text{ mA})} = f(I_F)$

Relative luminous intensity

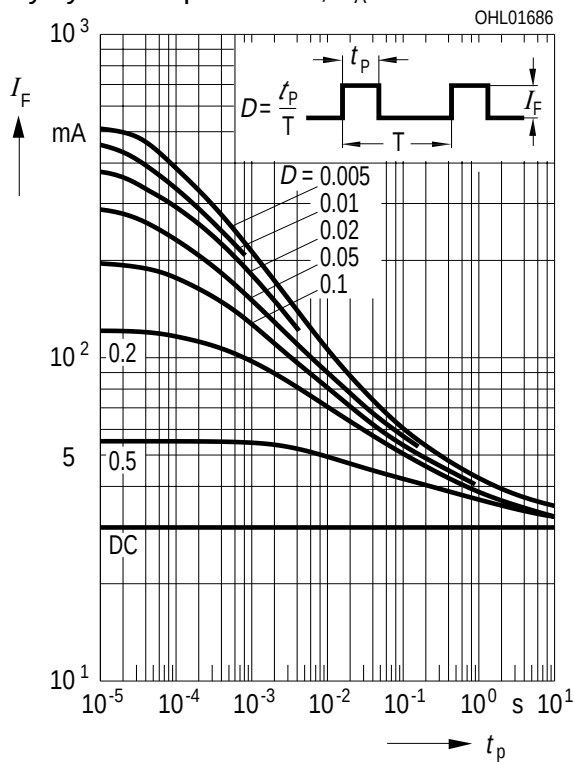
$T_A = 25^\circ\text{C}$



Zulässige Impulsbelastbarkeit $I_F = f(t_p)$

Permissible pulse handling capability

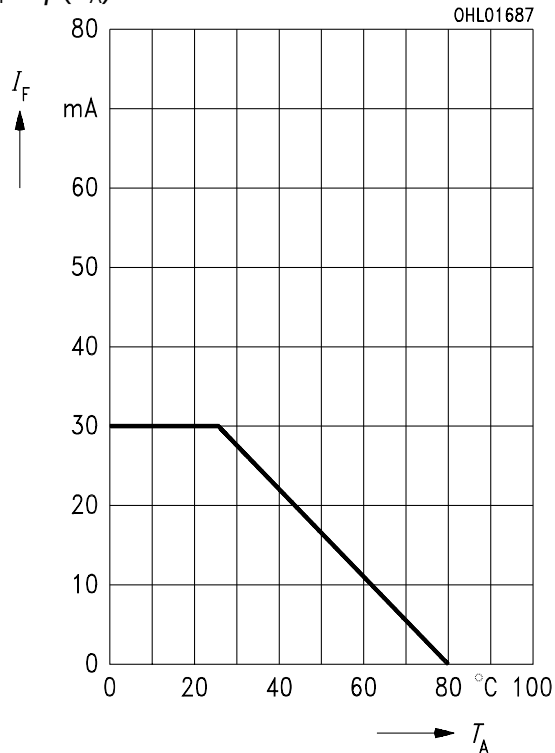
Duty cycle $D = \text{parameter}$, $T_A = 25^\circ\text{C}$



Maximal zulässiger Durchlaßstrom

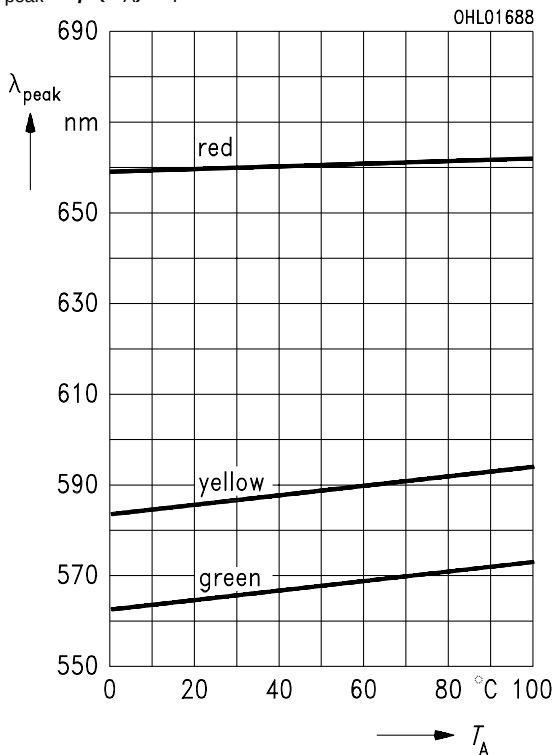
Max. permissible forward current

$I_F = f(T_A)$



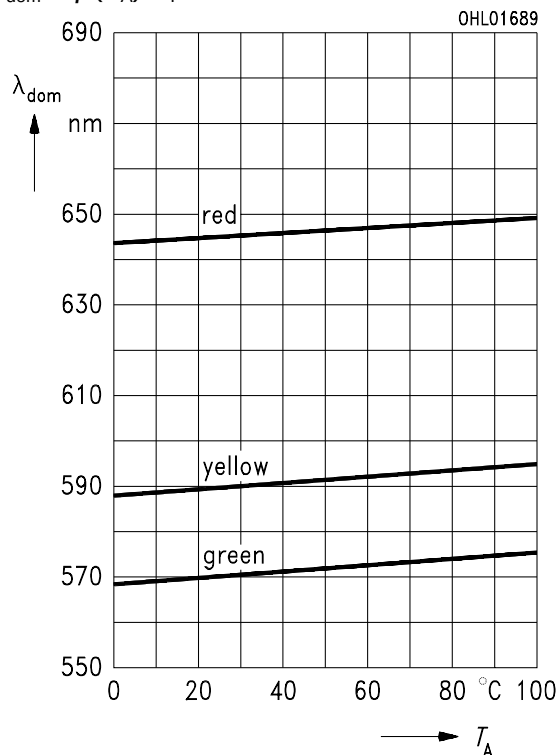
Wellenlänge der Strahlung
Wavelength at peak emission

$\lambda_{\text{peak}} = f(T_A), I_F = 20 \text{ mA}$



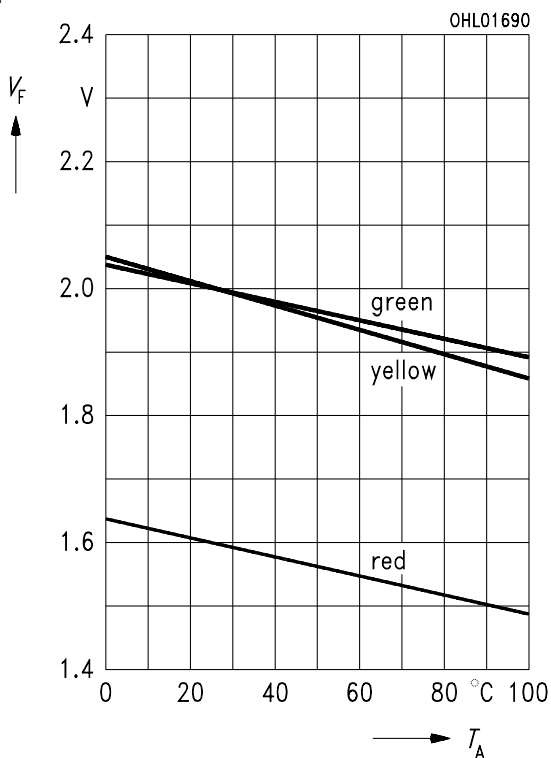
Dominantwellenlänge
Dominant wavelength

$\lambda_{\text{dom}} = f(T_A), I_F = 20 \text{ mA}$



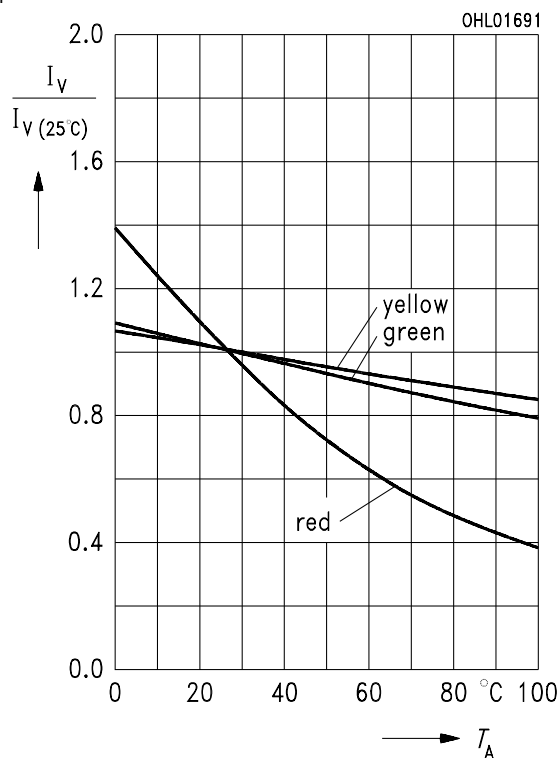
Durchlaßspannung $V_F = f(T_A)$
Forward voltage

$I_F = 10 \text{ mA}$

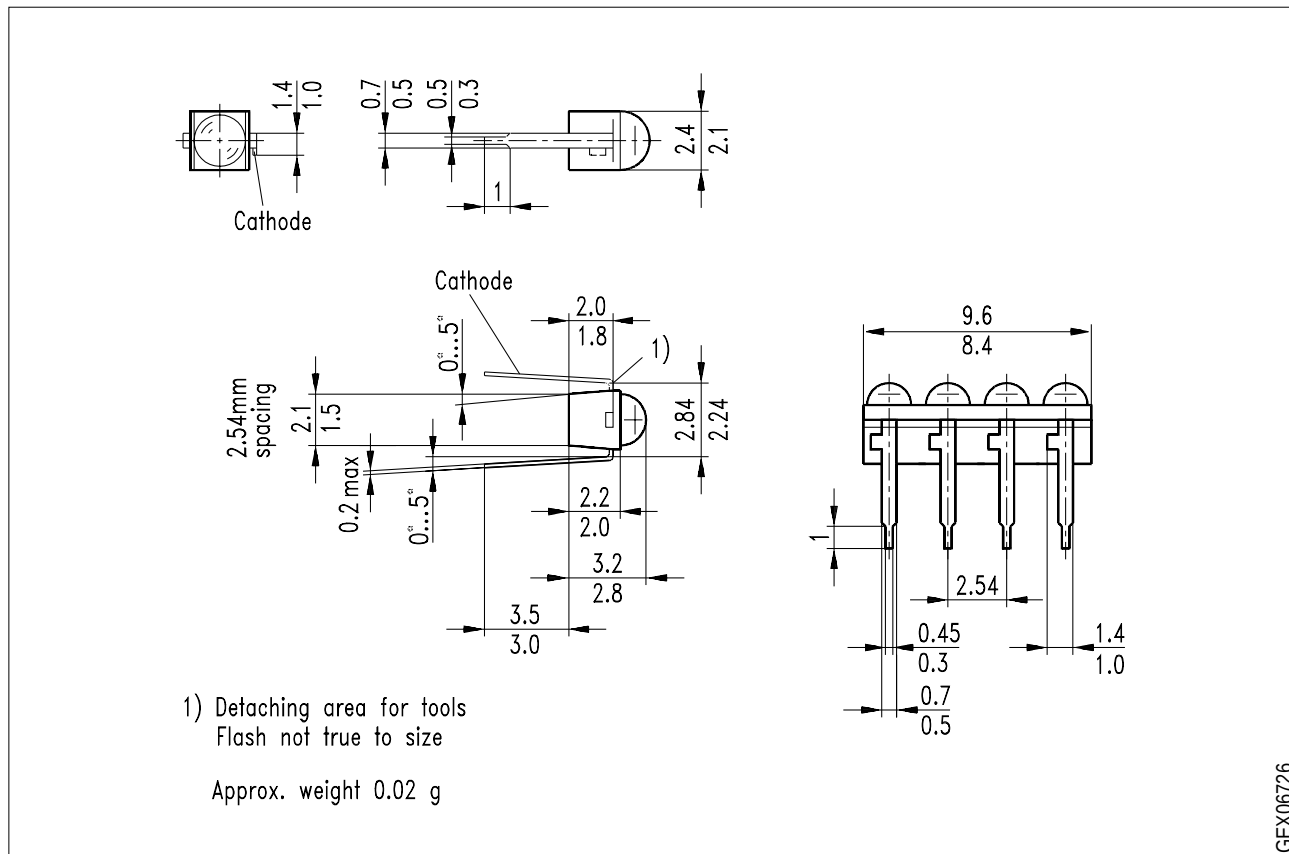


Relative Lichtstärke $I_V/I_{V(25^\circ\text{C})} = f(T_A)$
Relative luminous intensity

$I_F = 10 \text{ mA}$



Maßzeichnung (Maße in mm, wenn nicht anders angegeben)
Package Outlines (Dimensions in mm, unless otherwise specified)



Kathodenkennzeichnung: Breiterer Lötspieß
Cathode mark: Broad solder lead

Zeile mit 4 Dioden (z. B. LR Z184)
Row with 4 diodes (e. g. LR Z184)